

As a below named inventor, I hereby declare that:

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled: **STRUCTURE FOR AND METHOD OF FABRICATING A HIGH-MOBILITY FIELD-EFFECT TRANSISTOR**

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DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATIONSend Correspondence to: Steven Fischman, Scully, Scott, Murphy & Presser400 Garden City Plaza, Garden City, New York 11510Direct Telephone Calls to: (name and telephone number) Steven Fischman (516) 762-4343Jack O. ChuFull name of sole or first inventorInventor's SignatureDate10-13-0344 Shelbourne Lane, Manhasset Hills, New York 11040ResidenceUnited States of AmericaCitizenshipsSame as ResidencePost Office AddressSteven J. KoesterFull name of second inventorInventor's SignatureDate10-12-035 Iroquois Road, Ossining, New York 10562ResidenceUnited States of AmericaCitizenshipSame as ResidencePost Office AddressQiqing C. OuyangFull name of third inventorInventor's SignatureDate10/13/2003138 Hitching Post Lane, Yorktown Heights, New York 10598ResidencePeoples Republic of ChinaCitizenshipSame as ResidencePost Office Address